NSN 5961-00-484-5149

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View Online at https://aerobasegroup.com/nsn/5961-00-484-5149 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.359 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to base voltage/static/emitter open and 450.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release5587 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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